







SN65LBC172, SN75LBC172

SLLS163F - JULY 1993 - REVISED APRIL 2024

SN65LBC172, SN75LBC172 Quadruple Low-Power Differential Line Driver

1 Features

- Exceeds or meets EIA standard RS-485
- Designed for high-speed multipoint transmission on long bus lines in noisy environments
- Supports data rates up to and exceeding ten million transfers per second
- · Provides a common-mode output voltage range of -7V to 12V
- Offers positive-and negative-current limiting
- Consumes low power to 1.5mA max (output disabled)
- Functions interchangeably with the SN75172

2 Applications

- Motor drives
- Factory automation and control

3 Description

The SN65LBC172 and SN75LBC172 are monolithic quadruple differential line drivers with three-state outputs. Both devices are designed to meet the requirements of EIA Standard RS-485. These devices are optimized for balanced multipoint bus transmission at data rates up to and exceeding 10 million bits per second. Each driver features wide positive and negative common- mode output voltage

> EN 12 2 **1**Y ∇ 3 ∇ **1Z** 6 2Y 5 **2Z** 10 **3Y** 11 **3Z** 14 **4Y** 15 13 **4Z** Logic Symbol^{†1}

ranges, current limiting, and thermal-shutdown circuitry which provides a party-line application in noisy environments. Both devices are designed using LinBiCMOS™, facilitating ultra-low power consumption and inherent robustness.

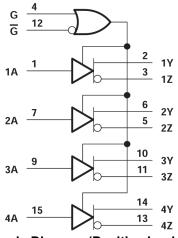
Both the SN65LBC172 and SN75LBC172 provide positive- and negative-current limiting and thermal shutdown for protection from line fault conditions on the transmission bus line. These devices offer optimum performance when used with the SN75LBC173 or SN75LBC175 quadruple receivers. The SN65LBC172 and SN75LBC172 are available in the 16-pin DIP package (N) and the 20-pin wide-body small-outline inline-circuit (SOIC) package (DW).

The SN75LBC172 is characterized for operation over the commercial temperature range of 0°C to 70°C. The SN65LBC172 is characterized over the industrial temperature range of -40°C to 85°C.

Package Information

PART NUMBER	PACKAGE ⁽¹⁾	PACKAGE SIZE ⁽²⁾		
SN65LBC172	DW (SOIC, 20)	10.3mm × 10.3mm		
SN75LBC172	N (PDIP 16)	19.3mm × 9.4mm		

- For more information, see Section 10.
- The package size (length × width) is a nominal value and includes pins, where applicable.



Logic Diagram (Positive Logic)

[†] This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

¹ Pin numbers shown are for the N package.



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4 Pin Configuration and Functions

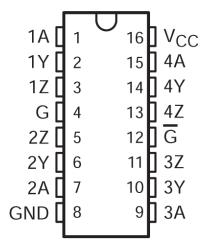


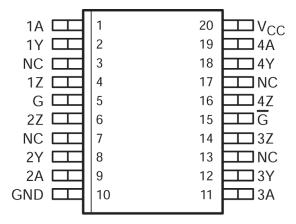
Figure 4-1. N Package (Top View)

Table 4-1. Pin Functions

PIN		- V2=(1)	DESCRIPTION		
NAME	NO.	TYPE ⁽¹⁾	DESCRIPTION		
1A	1	I	Driver 1 input		
1Y	2	0	Driver 1 output		
1Z	3	0	Driver 1 inverted output		
G	4	I	Active high enable all drivers		
2Z	5	0	Driver 2 inverted output		
2Y	6	0	river 2 output		
2A	7	I	Driver 2 input		
GND	8	G	Ground pin		
3A	9	I	Driver 3 input		
3Y	10	0	Driver 3 output		
3Z	11	0	Driver 3 inverted output		
G	12	I	Active low enable all drivers		
4Z	13	0	Driver 4 inverted output		
4Y	14	0	Driver 4 output		
4A	15	0	Driver 4 input		
V _{CC}	16	Р	Power pin		

(1) I = Input, O = Output, I/O = Input or Output, G = Ground, P = Power.





NC - No internal connection

Figure 4-2. DW Package (Top View)

Table 4-2. Pin Functions

PIN		TYPE ⁽¹⁾	DESCRIPTION			
NAME	NO.	ITPE	DESCRIPTION			
1A	1	I	Driver 1 input			
1Y	2	0	ver 1 output			
NC	3	-	No Internal Connection			
1Z	4	0	Driver 1 inverted output			
G	5	I	Active high enable all drivers			
2Z	6	0	Driver 2 inverted output			
NC	7	-	No Internal Connection			
2Y	8	0	Driver 2 output			
2A	9	I	Driver 2 input			
GND	10	G	Ground pin			
3A	11	I	Driver 3 input			
3Y	12	0	Driver 3 output			
NC	13	-	No Internal Connection			
3Z	14	0	Driver 3 inverted output			
G	15	I	Active low enable all drivers			
4Z	16	0	Driver 4 inverted output			
NC	17	_	No Internal Connection			
4Y	18	0	Driver 4 output			
4A	19	I	Driver 4 input			
V _{CC}	20	Р	Power pin			

⁽¹⁾ I = Input, O = Output, I/O = Input or Output, G = Ground, P = Power.



5 Specifications

5.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)(1)

		MIN	MAX	UNIT		
V _{CC}	Supply voltage range, (see ⁽³⁾)	-0.3	7	V		
Vo	Output voltage range	-10	15	V		
VI	Voltage range at A, G, G	-0.3	V _{CC} + 0.5	V		
P _D	Continuous power dissipation		Internally limited ⁽²⁾			
T _{stg}	Storage temperature range	-65	150	°C		
T _{LEAD}	Lead temperature 1,6mm (1/16 inch) from case for 10 seconds		260	°C		

⁽¹⁾ Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

5.2 Recommended Operating Conditions

		MIN	NOM	MAX	UNIT	
Supply voltage, V _{CC}	4.75	5	5.25	V		
High-level input voltage, V _{IH}		2			V	
Low-level input voltage, V _{IL}			0.8	V		
Voltage at any bus terminal (separately or common mode), V _O	Y or Z	-7		12	V	
High-level output current, I _{OH}	Y or Z			-60	mA	
Low-level output current, I _{OL}	Y or Z		60			
Continuous total power dissipation		Se	e Dissip	ation R	ating Table	
Junction temperature, T _J				140	°C	
Operating free circtemperature T	SN65LBC172	-40		85	°C	
Operating free-air temperature, T _A	SN75LBC172	0		70	L L	

5.3 Dissipation Rating Table

PACKAGE	THERMAL MODEL $T_A < 25^{\circ}\text{C POWER}$ DERATING FACTOR ABOVE $T_A = 25^{\circ}\text{C}$		T _A = 70°C POWER RATING	T _A = 85°C POWER RATING	
DW	Low K ⁽¹⁾	1094mW	10.4mW/°C	625mW	469mW
DVV	High K ⁽²⁾	1669mW	15.9mW/°C	954mW	715mW
N		1150mW	9.2mW/°C	736mW	598mW

⁽¹⁾ In accordance with the low effective thermal conductivity metric definitions of EIA/JESD 51-3.

⁽²⁾ The maximum operating junction temperature is internally limited. Use the dissipation rating table to operate below this temperature.

⁽³⁾ All voltage values are with respect to GND.

⁽²⁾ In accordance with the high effective thermal conductivity metric definitions of EIA/JESD 51-7.



5.4 Thermal Information

	THERMAL METRIC(1)	N (PDIP)	DW (SOIC)	UNIT
	THERMAL METRIC	16 PINS	20 PINS	UNII
R _{θJA}	Junction-to-ambient thermal resistance	60.6	66.8	°C/W
R ₀ JC(top)	Junction-to-case (top) thermal resistance	48.1	34.4	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	40.6	39.7	°C/W
Ψ_{JT}	Junction-to-top characterization parameter	27.5	8.9	°C/W
ΨЈВ	Junction-to-board characterization parameter	40.3	39	°C/W
$R_{\theta JC(bot)}$	Junction-to-case (bottom) thermal resistance	n/a	n/a	°C/W

⁽¹⁾ For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report.

5.5 Electrical Characteristics

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

	PARAMETER	TEST	CONDITIONS	MIN	TYP (1)	MAX	UNIT
V _{IK}	Input clamp voltage	I _I = -18mA	I _I = -18mA			-1.5	V
		$R_L = 54\Omega$ See	SN65LBC172	1.1	1.8	5	
IV 1	Differential output voltage ⁽²⁾	Figure 6-1	SN75LBC172	1.5	1.8	5	V
V _{OD}	Differential output voltage	$R_L = 60\Omega$, See	SN65LBC172	1.1	1.7	5	V
		Figure 6-2	SN75LBC172	1.5	1.7	5	
Δ V _{OD}	Change in magnitude of common-mode output voltage ⁽³⁾					±0.2	V
V _{OC}	Common-mode output voltage	$R_L = 54\Omega$,	See Figure 6-1	-1		3	V
Δ V _{OC}	Change in magnitude of common-mode output voltage ⁽³⁾					±0.2	V
Io	Output current with power off	V _{CC} = 0,	V _O = - 7V to 12V			± 100	μA
I _{OZ}	High-impedance-state output current	V _O = - 7V to 12	V			± 100	μA
I _{IH}	High-level input current	V _I = 2.4V				-100	μA
I _{IL}	Low-level input current	V _I = 0.4V	V _I = 0.4V			-100	μA
Ios	Short-circuit output current	V _O = -7V to 12V	V _O = -7V to 12V			±250	mA
ı	Supply current (all drivers)	No load	Outputs enabled			7	mA
I _{CC}	Supply current (all drivers)	NO IOAU	Outputs disabled			1.5	шА

All typical values are at V_{CC} = 5V and T_A = 25°C. The minimum V_{OD} specification does not fully comply with EIA-485 at operating temperatures below 0°C. The lower output signal should be used to determine the maximum signal-transmission distance.

 $[\]Delta_{|VOD}|$ and $\Delta|V_{OC}|$ are the changes in magnitude of V_{OD} and V_{OC} , respectively, that occur when the input changes from a high level to a low level.



5.6 Switching Characteristics

 $V_{CC} = 5 \text{ V}, T_A = 25^{\circ}\text{C}$

	PARAMETER	TEST CO	MIN	TYP	MAX	UNIT	
t _{d(OD)}	Differential output delay time	D - 540	Con Figure 6.2	2	11	20	
t _{t(OD)}	Differential output transition time	$R_L = 54\Omega$,	See Figure 6-3	9	15	25	ns
t _{PZH}	Output enable time to high level	$R_L = 110\Omega$,	See Figure 6-4		20	30	ns
t _{PZL}	Output enable time to low level	$R_L = 110\Omega$,	See Figure 6-5		21	30	ns
t _{PHZ}	Output disable time from high level	$R_L = 110\Omega$,	See Figure 6-4		48	70	ns
t _{PLZ}	Output disable time from low level	$R_L = 110\Omega$,	See Figure 6-5		21	30	ns



5.7 Typical Characteristics

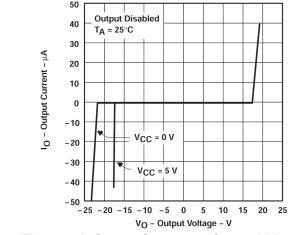


Figure 5-1. Output Current vs Output Voltage

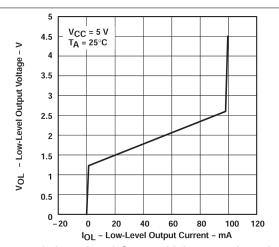


Figure 5-2. Low-level Output Voltage vs Low-level Output Current

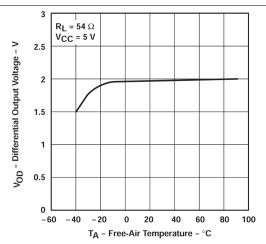


Figure 5-3. Differential Output Voltage vs Free-air Temperature

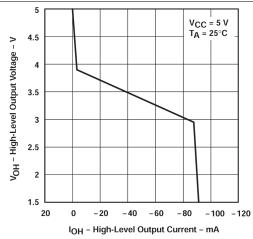


Figure 5-4. High-level Output Voltage vs High-level Output Current

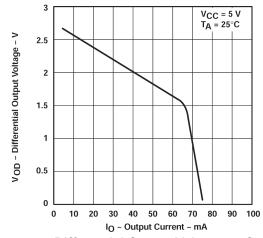


Figure 5-5. Differential Output Voltage vs Output
Current

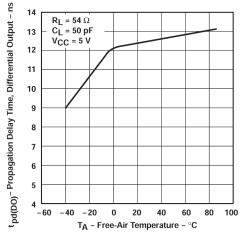


Figure 5-6. Propagation Delay Time, Differential Output vs Free-air Temperature



6 Parameter Measurement Information

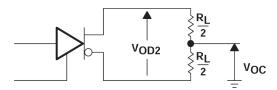
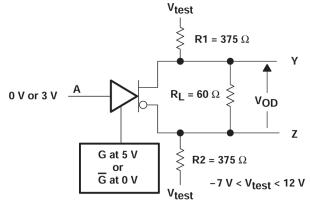
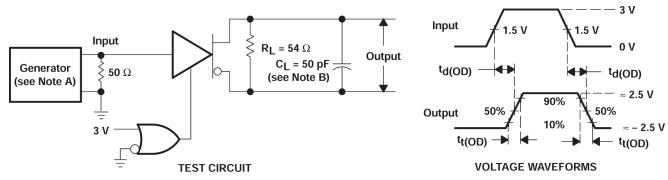


Figure 6-1. Differential and Common-Mode Output Voltages



- A. The input pulse is supplied by a generator having the following characteristics: PRR \leq 1 MHz, duty cycle = 50%, $t_r \leq$ 5 ns, $t_f \leq$ 5 ns, $Z_O =$ 50 Ω .
- B. C_L includes probe and stray capacitance.

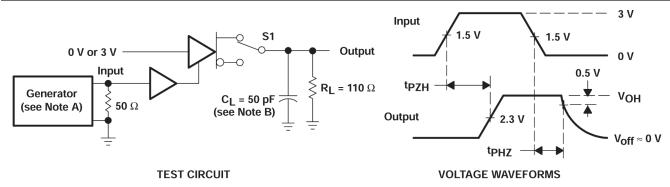
Figure 6-2. Driver V_{OD} Test Circuit



- A. The input pulse is supplied by a generator having the following characteristics: PRR ≤ 1 MHz, duty cycle = 50%, t_f ≤ 5 ns, t_f ≤ 5 ns, Z_O = 50 Ω.
- B. C_L includes probe and stray capacitance.

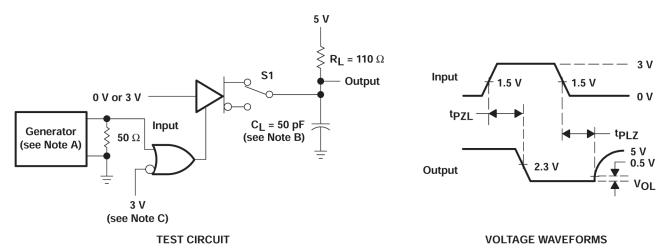
Figure 6-3. Driver Differential-Output Test Circuit and Delay and Transition-Time Waveforms





- A. The input pulse is supplied by a generator having the following characteristics: PRR ≤ 1 MHz, duty cycle = 50%, t_f ≤ 5 ns, t_f ≤ 5 ns, Z_O = 50 Ω.
- B. C_L includes probe and stray capacitance.

Figure 6-4. t_{PZH} and t_{PHZ} Test Circuit and Voltage Waveforms



- A. The input pulse is supplied by a generator having the following characteristics: PRR ≤ 1 MHz, duty cycle = 50%, $t_r \le 5$ ns, $t_f \le 5$ n
- B. C_L includes probe and stray capacitance
- C. To test the active-low enable \overline{G} , ground G and apply an inverted waveform to \overline{G} .

Figure 6-5. t_{PZL} and t_{PLZ} Test Circuit and Waveforms

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7 Detailed Description

7.1 Thermal Characteristics of Ic Packages

 Θ_{JA} (Junction-to-Ambient Thermal Resistance) is defined as the difference in junction temperature to ambient temperature divided by the operating power

 Θ_{JA} is NOT a constant and is a strong function of

- the PCB design (50% variation)
- altitude (20% variation)
- device power (5% variation)

 Θ_{JA} can be used to compare the thermal performance of packages if the specific test conditions are defined and used. Standardized testing includes specification of PCB construction, test chamber volume, sensor locations, and the thermal characteristics of holding fixtures. Θ_{JA} is often misused when it is used to calculate junction temperatures for other installations.

TI uses two test PCBs as defined by JEDEC specifications. The low-k board gives *average* in-use condition thermal performance and consists of a single trace layer 25mm long and 2 oz thick copper. The high-k board gives *best case* in-use condition and consists of two 1-oz buried power planes with a single trace layer 25mm long with 2-oz thick copper. A 4% to 50% difference in Θ_{JA} can be measured between these two test cards

 Θ_{JC} (Junction-to-Case Thermal Resistance) is defined as difference in junction temperature to case divided by the operating power. It is measured by putting the mounted package up against a copper block cold plate to force heat to flow from die, through the mold compound into the copper block.

 Θ_{JC} is a useful thermal characteristic when a heatsink is applied to package. It is NOT a useful characteristic to predict junction temperature as it provides pessimistic numbers if the case temperature is measured in a non-standard system and junction temperatures are backed out. It can be used with Θ_{JB} in 1-dimensional thermal simulation of a package system.

 Θ_{JB} (Junction-to-Board Thermal Resistance) is defined to be the difference in the junction temperature and the PCB temperature at the center of the package (closest to the die) when the PCB is clamped in a cold-plate structure. Θ_{JB} is only defined for the high-k test card.

 Θ_{JB} provides an overall thermal resistance between the die and the PCB. Including a bit for the PCB thermal resistance (especially for BGAs with thermal balls), and can be used for simple 1-dimensional network analysis of package system (see Figure 7-1).

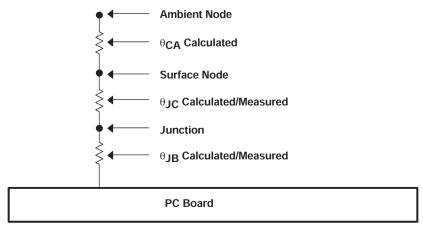


Figure 7-1. Thermal Resistance



7.2 Device Functional Modes

Table 7-1. Function Table (Each Driver)

INPUT A	ENAB	LES ⁽¹⁾	OUTPUTS		
INPULA	G	G	Y	Z	
Н	Н	X	Н	L	
L	Н	X	L	Н	
Н	X	L	Н	L	
L	X	L	L	Н	
X	L	Н	Z	Z	

(1) H = high level, L = low level, X = irrelevant, Z = high impedance (off)

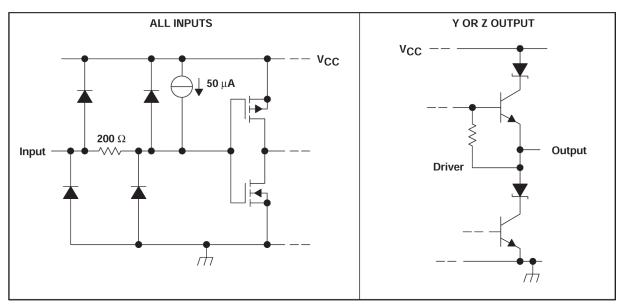


Figure 7-2. Schematic Diagrams of Inputs and Outputs



8 Device and Documentation Support

TI offers an extensive line of development tools. Tools and software to evaluate the performance of the device, generate code, and develop solutions are listed below.

8.1 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. Click on *Notifications* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

8.2 Support Resources

TI E2E[™] support forums are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

Linked content is provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

8.3 Trademarks

LinBiCMOS[™] and TI E2E[™] are trademarks of Texas Instruments. All trademarks are the property of their respective owners.

8.4 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

8.5 Glossary

TI Glossary

This glossary lists and explains terms, acronyms, and definitions.

9 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

10 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

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PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
	(1)		g		4.,	(2)	(6)	(3)		(4/3)	
SN65LBC172DW	ACTIVE	SOIC	DW	20	25	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	SN65LBC172	Samples
SN65LBC172N	ACTIVE	PDIP	N	16	25	RoHS & Green	NIPDAU	N / A for Pkg Type	-40 to 85	SN65LBC172N	Samples
SN75LBC172DW	OBSOLETE	SOIC	DW	20		TBD	Call TI	Call TI	0 to 70	SN75LBC172	
SN75LBC172DWR	ACTIVE	SOIC	DW	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	SN75LBC172	Samples
SN75LBC172N	ACTIVE	PDIP	N	16	25	RoHS & Green	NIPDAU	N / A for Pkg Type	0 to 70	SN75LBC172N	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead finish/Ball material Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and

PACKAGE OPTION ADDENDUM

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continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

OTHER QUALIFIED VERSIONS OF SN75LBC172:

• Military : SN55LBC172

NOTE: Qualified Version Definitions:

• Military - QML certified for Military and Defense Applications

PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

	Device	_	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
L	SN75LBC172DWR	SOIC	DW	20	2000	330.0	24.4	10.8	13.3	2.7	12.0	24.0	Q1

PACKAGE MATERIALS INFORMATION

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*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN75LBC172DWR	SOIC	DW	20	2000	367.0	367.0	45.0

PACKAGE MATERIALS INFORMATION

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TUBE



*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
SN65LBC172DW	DW	SOIC	20	25	507	12.83	5080	6.6
SN65LBC172DW	DW	SOIC	20	25	506.98	12.7	4826	6.6
SN65LBC172N	N	PDIP	16	25	506	13.97	11230	4.32
SN75LBC172DW	DW	SOIC	20	25	507	12.83	5080	6.6
SN75LBC172DW	DW	SOIC	20	25	506.98	12.7	4826	6.6
SN75LBC172N	N	PDIP	16	25	506	13.97	11230	4.32

N (R-PDIP-T**)

PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- The 20 pin end lead shoulder width is a vendor option, either half or full width.





SOIC



NOTES:

- 1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.43 mm per side.
- 5. Reference JEDEC registration MS-013.



SOIC



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SOIC



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



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